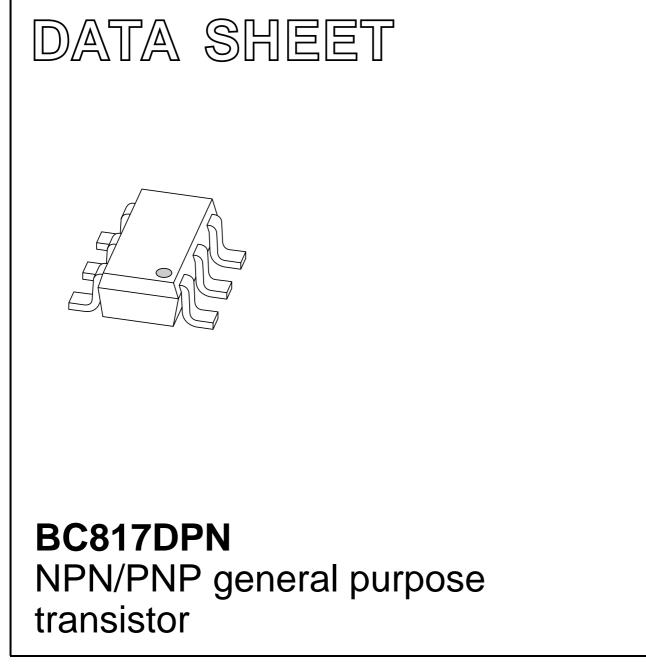
# DISCRETE SEMICONDUCTORS



Product data sheet Supersedes data of 2002 Aug 09 2002 Nov 22



## BC817DPN

#### FEATURES

- High current (500 mA)
- 600 mW total power dissipation
- Replaces two SOT23 packaged transistors on same PCB area.

#### APPLICATIONS

- · General purpose switching and amplification
- Complementary driver
- Half and full bridge driver.

#### DESCRIPTION

NPN/PNP transistor pair in a SOT457 (SC-74) plastic package.

#### MARKING

TYPE NUMBER	MARKING CODE			
BC817DPN	N4			

## QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT	
V <sub>CEO</sub>	collector-emitter voltage	45	V	
I <sub>C</sub>	collector current (DC)	500	mA	
I <sub>CM</sub>	peak collector current	1	А	

#### PINNING

PIN	DESCRIPTION	
1, 4	emitter	TR1; TR2
2, 5	base	TR1; TR2
6, 3	collector	TR1; TR2

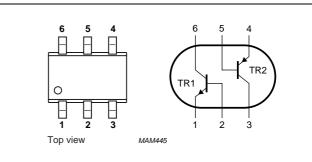


Fig.1 Simplified outline (SOT457) and symbol.

#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT	
Per transi	Per transistor; for the PNP transistor with negative polarity					
V <sub>CBO</sub>	collector-base voltage	open emitter	_	50	V	
V <sub>CEO</sub>	collector-emitter voltage	open base	-	45	V	
V <sub>EBO</sub>	emitter-base voltage	open collector	-	5	V	
I <sub>C</sub>	collector current (DC)		_	500	mA	
I <sub>CM</sub>	peak collector current		_	1	А	
I <sub>BM</sub>	peak base current		_	200	mA	
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \text{ °C}; \text{ note } 1$	-	370	mW	
T <sub>stg</sub>	storage temperature		-65	+150	°C	
Ti	junction temperature		_	150	°C	
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C	
Per device	9			•	•	
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C; note 1	-	600	mW	
r tot		$T_{amb} \ge 23$ C, Hole T	-	000		

Note

1. Device mounted on a printed-circuit board; single sided copper; tinplated; mounting pad for collector 1 cm<sup>2</sup>.

## BC817DPN

## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	208	K/W

#### Note

1. Device mounted on a printed-circuit board; single sided copper; tinplated; mounting pad for collector 1 cm<sup>2</sup>.

#### CHARACTERISTICS

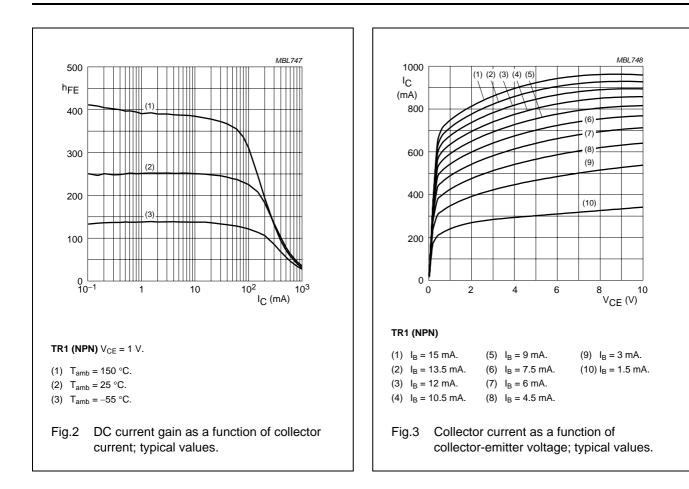
 $T_{amb}$  = 25 °C unless otherwise specified.

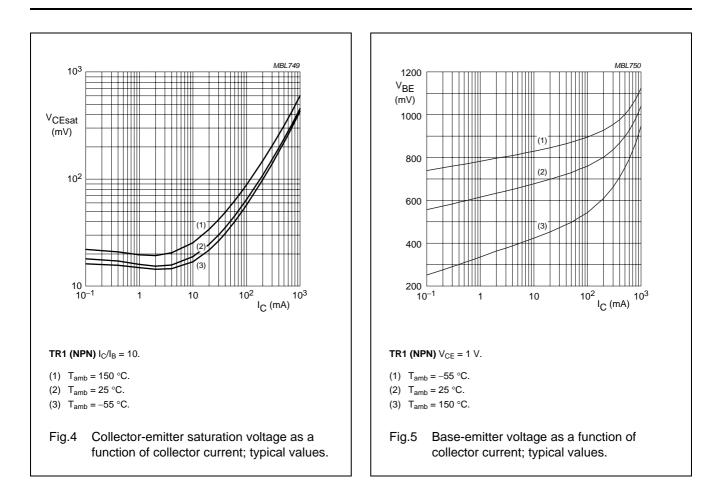
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Per transi	stor unless otherwise specified; fo	or the PNP transistor with negative	polarity	/		
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = 20 \text{ V}; I_E = 0$	_	_	100	nA
		V <sub>CB</sub> = 20 V; I <sub>E</sub> = 0; T <sub>j</sub> = 150 °C	_	_	5	μA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 5 V; I_{C} = 0$	-	_	100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 1 V; I <sub>C</sub> = 100 mA; note 1	160	_	400	
		V <sub>CE</sub> = 1 V; I <sub>C</sub> = 500 mA; note 1	40	_	_	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_{C} = 500 \text{ mA}; I_{B} = 50 \text{ mA}; \text{ note } 1$	-	_	700	mV
V <sub>BE</sub>	base-emitter voltage	$V_{CE} = 1 V; I_C = 500 mA;$ notes 1 and 2	-	-	1.2	V
NPN trans	istor					
Cc	collector capacitance	V <sub>CB</sub> = 10 V; I <sub>E</sub> = I <sub>e</sub> = 0; f = 1 MHz	-	5	-	pF
f <sub>T</sub>	transition frequency	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 10 mA; f = 100 MHz	100	-	-	MHz
PNP trans	istor					
C <sub>c</sub>	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = I_e = 0; f = 1 \text{ MHz}$	_	9	_	pF
f <sub>T</sub>	transition frequency	V <sub>CE</sub> = -5 V; I <sub>C</sub> = -10 mA; f = 100 MHz	80	-	-	MHz

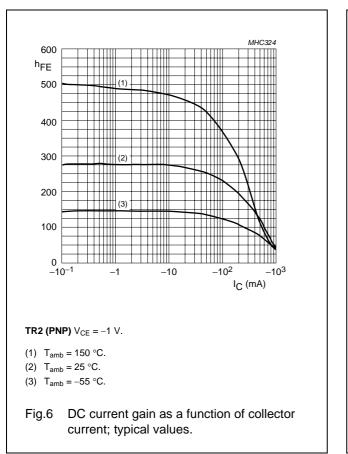
#### Notes

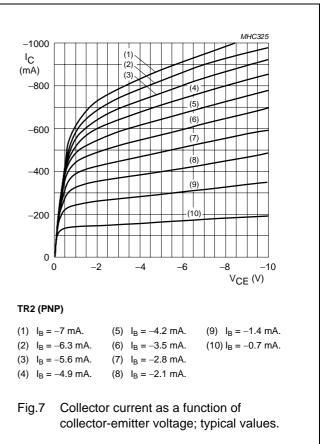
1. Pulse test:  $t_p \leq 300~\mu\text{s};~\delta \leq 0.02.$ 

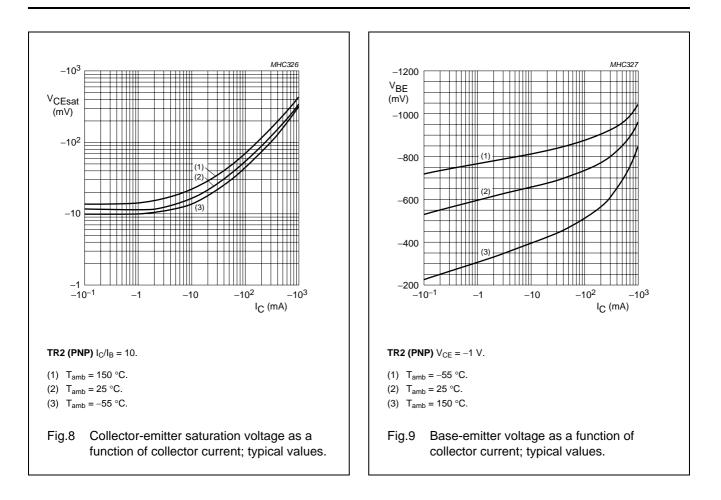
2.  $V_{BE}$  decreases by approximately -2 mV/K with increasing temperature.











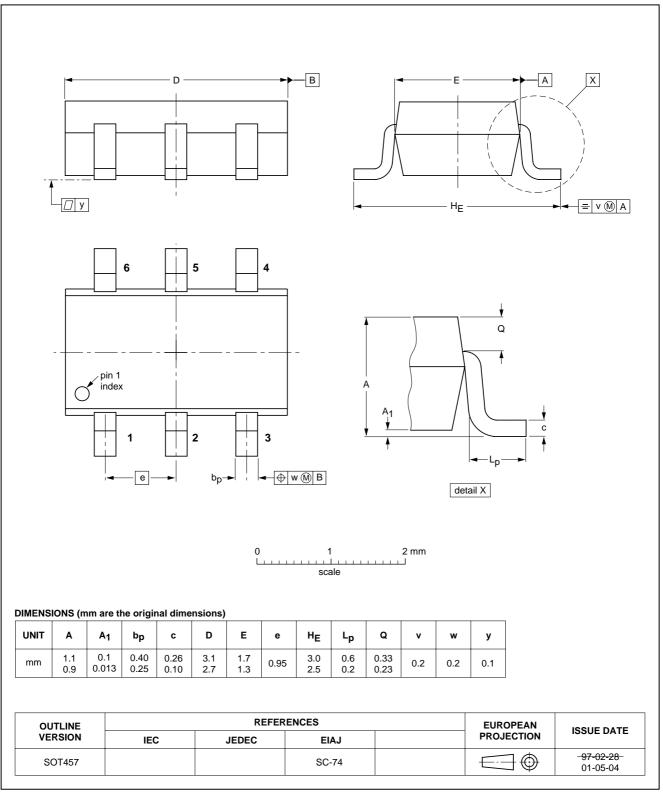
### Product data sheet

BC817DPN

# NPN/PNP general purpose transistor

#### PACKAGE OUTLINE

## Plastic surface mounted package; 6 leads



SOT457

## BC817DPN

#### DATA SHEET STATUS

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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